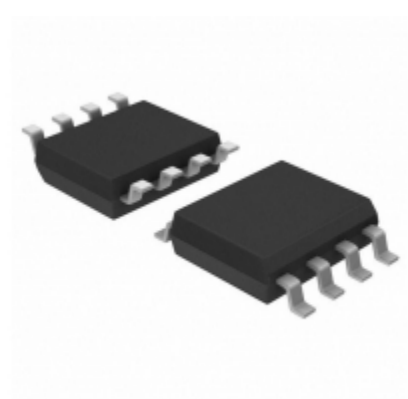


| | |
|-------------------------|--|
| SI4814BDY-T1-GE3 | |
| Teilenummer | SI4814BDY-T1-GE3 |
| Hersteller | Vishay / Siliconix |
| Beschreibung | MOSFET 2N-CH 30V 10A 8SOIC |
| Verfügbare Menge | 500 pcs in stock |
| Datenblätter | |
| SI4814BDY-T1-GE3 Price | Preis und Lieferzeit online anfordern or Email us: Info@ariat-tech.com |


[EIN ANGEBOT BEKOMMEN](#)

| Technische Information von SI4814BDY-T1-GE3 | | | |
|--|------------------------------------|-------------------------------------|---|
| Hersteller-Teilenummer | SI4814BDY-T1-GE3 | Kategorie | Diskrete Halbleiterprodukte |
| Hersteller | Vishay / Siliconix | Beschreibung | MOSFET 2N-CH 30V 10A 8SOIC |
| Paket / Fall | Tape & Reel (TR) | Verfügbare Menge | 500 |
| VGS (th) (Max) @ Id | 3V @ 250µA | Supplier Device-Gehäuse | 8-SO |
| Serie | LITTLE FOOT® | Rds On (Max) @ Id, Vgs | 18 mOhm @ 10A, 10V |
| Leistung - max | 3.3W, 3.5W | Verpackung | Tape & Reel (TR) |
| Verpackung / Gehäuse | 8-SOIC (0.154", 3.90mm Width) | Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount | Eingabekapazität (Ciss) (Max) @ Vds | - |
| Gate Charge (Qg) (Max) @ Vgs | 10nC @ 4.5V | Typ FET | 2 N-Channel (Half Bridge) |
| FET-Merkmal | Logic Level Gate | Drain-Source-Spannung (Vdss) | 30V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 10A, 10.5A | | |

SI4814BDY-T1-GE3 500 pcs Neu und original auf Lager, SI4814BDY-T1-GE3-Bestand finden, Datenblatt, PDF, Inventar bei Ariat-Tech.com online, SI4814BDY-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen bestellen. Anfrage SI4814BDY-T1-GE3: Info@Ariat-Tech.com

| Zugehörige Teile für SI4814BDY-T1-GE3 | | | | |
|---------------------------------------|-------------------------------------|------------------------------|------------------------------|------------|
| Bild | Teilenummer | Beschreibung | Hersteller | Menge |
| | SI4816BDY-T1-GE3 | MOSFET 2N-CH 30V 5.8A 8-SOIC | Electro-Films (EFI) / Vishay | 757 pcs |
| | SI4816BDY | SI4816BDY SI | SI | 50000 pcs |
| | SI4812DY-T1-E3 | SI4812DY-T1-E3 VISHAY | VISHAY | 17585 pcs |
| | SI4816BDY-T1-GE3 | MOSFET 2N-CH 30V 5.8A 8-SOIC | Vishay Siliconix | 757 pcs |
| | SI4814 | SI4814 VISHAY | VISHAY | 56 pcs |
| | SI4816BDY-T1-E3 | MOSFET 2N-CH 30V 5.8A 8-SOIC | Vishay Siliconix | 1000 pcs |
| | SI4814BDY-T1-GE3 | MOSFET 2N-CH 30V 10A 8SOIC | Electro-Films (EFI) / Vishay | 500 pcs |
| | SI4812DY-T1 | SI4812DY-T1 VISHAY | VISHAY | 33750 pcs |
| | SI4814DY-T1 | SI4814DY-T1 VISHAY | VISHAY | 312 pcs |
| | SI4816BDY-T1-E3 | SI4816BDY-T1-E3. VIS | VIS | 164 pcs |
| | SI4814BDY | SI4814BDY SI | SI | 40 pcs |
| | SI4812BDY-T1-GE3 | MOSFET N-CH 30V 7.3A 8-SOIC | Vishay Siliconix | 325000 pcs |
| | SI4814BDY-T1-E3 | MOSFET 2N-CH 30V 10A 8SOIC | Electro-Films (EFI) / Vishay | 9855 pcs |
| | SI4814DY | SI4814DY VISHAY | VISHAY | 25000 pcs |
| | SI4812BDY-T1-GE3 | MOSFET N-CH 30V 7.3A 8-SOIC | Electro-Films (EFI) / Vishay | 325000 pcs |
| | SI4814DY-T1-E3 | SI4814DY-T1-E3 VISHAY | VISHAY | 55000 pcs |
| | SI4816BDY-T1-E3 | MOSFET 2N-CH 30V 5.8A 8-SOIC | Electro-Films (EFI) / Vishay | 1000 pcs |
| | SI4812DY-T1-E3 SOP8 | SI4812DY-T1-E3 SOP8 VISHAY | VISHAY | 2400 pcs |
| | SI4814BDY-T1-E3 | MOSFET 2N-CH 30V 10A 8SOIC | Vishay Siliconix | 9855 pcs |
| | SI4812DY | SI4812DY VISHAY | VISHAY | 26285 pcs |

| | | | |
|-----------------------------|---|-------------------------------|-----------------------------------|
| SI4814BDY-T1-GE3-Lager | SI4814BDY-T1-GE3 Preis | SI4814BDY-T1-GE3-Elektronik | SI4814BDY-T1-GE3-Komponenten |
| SI4814BDY-T1-GE3 Inventar | SI4814BDY-T1-GE3 Digikkey | Lieferant SI4814BDY-T1-GE3 | SI4814BDY-T1-GE3 online bestellen |
| Anfrage SI4814BDY-T1-GE3 | SI4814BDY-T1-GE3-Bild | SI4814BDY-T1-GE3 Bild | SI4814BDY-T1-GE3 PDF |
| SI4814BDY-T1-GE3 Datenblatt | SI4814BDY-T1-GE3 Datenblatt herunterladen | Hersteller Vishay / Siliconix | |

Händler für Elektronikkomponenten - IC-Chips & IGBT-Modullieferant.

Angebotsanfrage E-Mail: Info@ariat-tech.com Webseite: <https://www.ariat-tech.com>

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